



BSN20

#### N-CHANNEL ENHANCEMENT MODE FIELD MOSFET

## **Product Summary**

V <sub>(BR)DSS</sub>	Rds(on)	I <sub>D</sub> T <sub>A</sub> = +25°C
50V	$1.8\Omega @ V_{GS} = 10V$	500mA
	2.0Ω @ V <sub>GS</sub> = 4.5V	450mA

### **Features and Benefits**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

## **Description and Applications**

This new generation MOSFET has been designed to minimize the onstate resistance (RDS(ON)) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

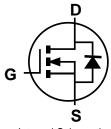
- Backlighting
- DC-DC Converters
- Power Management Functions

### **Mechanical Data**

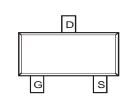
- Case: SOT23
- Case Material: Molded Plastic "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)







Internal Schematic



Top View

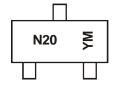
## **Ordering Information** (Note 4)

Part Number	Qualification	Case	Packaging
BSN20-7	Standard	SOT23	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



 $\begin{array}{l} \text{N20 = Product Type Marking Code} \\ \text{YM = Date Code Marking} \\ \text{Y or } \overline{\text{Y}} = \text{Year (ex: } G = 2019) \\ \text{M = Month (ex: } 9 = \text{September)} \end{array}$ 

Date Code Key

- 4	Date Code i	\Cy													
	Year	2009	-	201	9 20	20 2	021	2022	2023		2024	2025	2026	2027	2028
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# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Chara	cteristic		Symbol	Value	Unit
Drain-Source Voltage			VDSS	50	V
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current @ T <sub>SP</sub> = +25°C (Note 5)	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +100°C	lo	500 300	mA
Pulsed Drain Current @ Tsp = +	25°C (Notes 5 & 6	)	IDM	1.2	A

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation, @T <sub>A</sub> = +25°C (Note 5)	PD	600	mW
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C (Note 5)	$R_{ heta JA}$	200	°C/W
Power Dissipation, @Tsp = +25°C (Note 5)	PD	920	mW
Thermal Resistance, @Tsp = +25°C (Note 5)	Rejsp	136	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

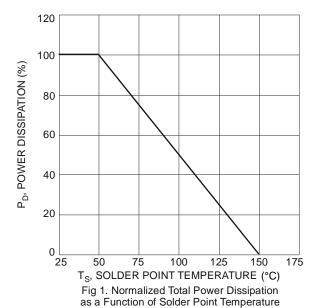
## Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

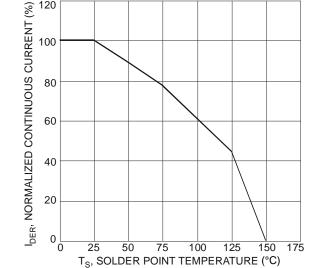
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)			•	•	•		
Drain-Source Breakdown Voltage	BVDSS	50	_	_	V	Vgs = 0V, ID = 250µA	
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	IDSS	_	_	0.5	μΑ	V <sub>DS</sub> = 50V, V <sub>GS</sub> = 0V	
Gate-Body Leakage	Igss	_	_	±100	nA	VGS = ±20V, VDS = 0V	
ON CHARACTERISTICS (Note 7)			•	•	•		
Gate Threshold Voltage	Vgs(TH)	0.4	1.0	1.5	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Static Drain-Source On-Resistance	RDS(ON)	_	1.3 1.6	1.8 2.0	Ω	V <sub>GS</sub> = 10V, I <sub>D</sub> = 0.22A V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 0.1A	
Forward Transfer Admittance	Y <sub>fs</sub>	40	320	_	mS	V <sub>DS</sub> = 10V, I <sub>D</sub> = 0.1A	
Diode Forward Voltage	$V_{SD}$	_	1.0	1.5	V	V <sub>G</sub> S = 0V, I <sub>S</sub> = 180mA	
Source (Diode Forward) Current	Is	_	_	194	mA	T <sub>SP</sub> = +25°C	
Peak Source (Diode Forward) Current	I <sub>SM</sub>	_	_	1.2	Α	T <sub>SP</sub> = +25°C	
DYNAMIC CHARACTERISTICS (Note 8)			•	•	•		
Input Capacitance	Ciss	-	21.8	40	pF		
Output Capacitance	Coss	_	5.6	15	pF	$V_{DS} = 10V, V_{GS} = 0V, f = 1.0MHz$	
Reverse Transfer Capacitance	Crss	_	3.3	10	pF		
Gate Resistance	$R_g$	_	49	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge	$Q_g$	_	800	_	pC	V 40V V 25V	
Gate-Source Charge	$Q_{gs}$	-	100	_	рC	$V_{GS} = 10V, V_{DD} = 25V,$ $I_{D} = 250 \text{mA}$	
Gate-Drain Charge	$Q_{gd}$	1	100	_	рC	- ID = 230IIIA	
Turn-On Delay Time	td(ON)	1	2.93	_	ns		
Turn-On Rise Time	t <sub>R</sub>	_	2.99	_	ns	$V_{DD} = 30V, V_{GEN} = 10V,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	9.45	_	ns	$R_L = 150\Omega, R_{GEN} = 50\Omega,$ $I_D = 0.2A$	
Turn-Off Fall Time	tF	_	8.3	ns			

Notes:

- Device mounted on FR-4 PCB, with minimum recommended pad layout.
   Repetitive rating, pulse width limited by junction temperature.
   Short duration pulse test used to minimize self-heating effect.
   Guaranteed by design. Not subject to production testing.



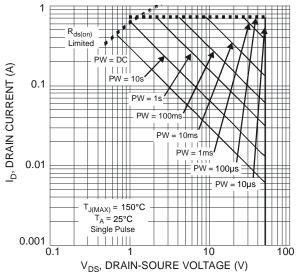


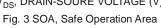


120

100

Fig 2. Normalized Continuous Current vs. Solder Point Temperature





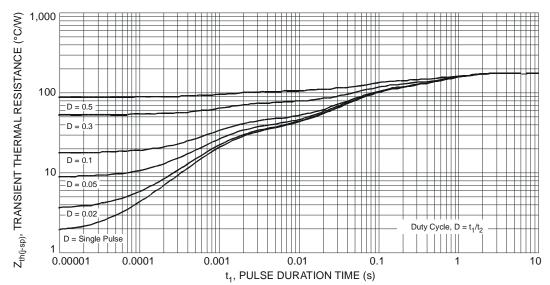
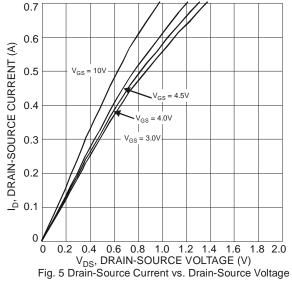
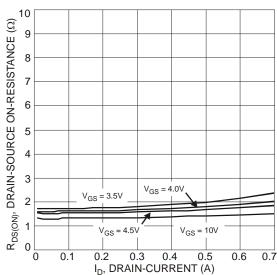
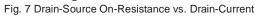


Fig. 4 Transient Thermal Response









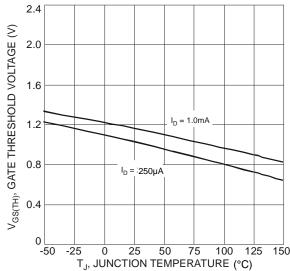
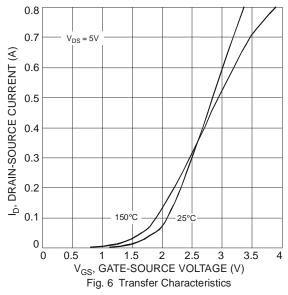


Fig. 9 Gate Threshold Voltage vs. Junction Temperature



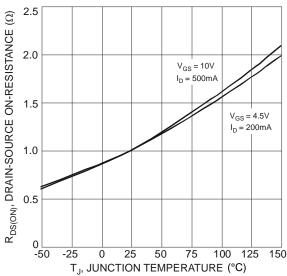
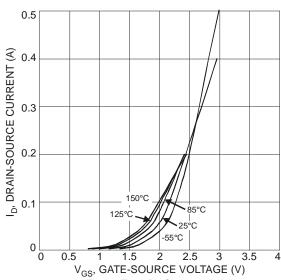
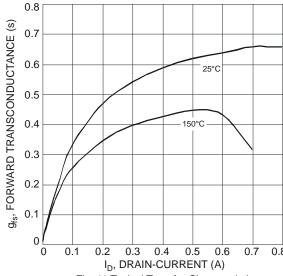
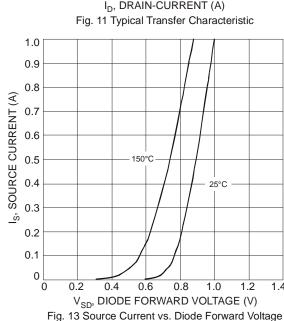


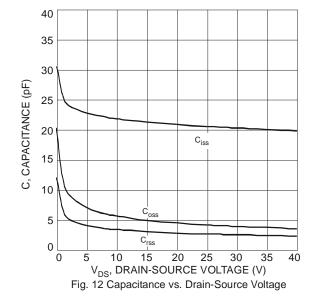
Fig. 8 Drain-Source On-Resistance vs. Junction Temperature









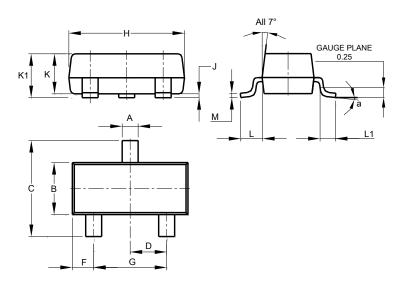




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23

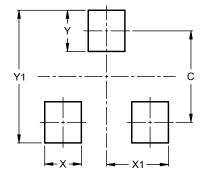


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Η	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Υ	0.9
Y1	2.9



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7 of 7

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